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- Theory
- Explanation
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- Example
- Shortcuts
- Previous Years Question With Solution

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	(P)		*	Micropro ces	-: 802:	* 					
							``				
	613	.	Before 1947 -	→ Vaccum	fubes,	1949) -> To	ransiston	· ·		
	<>> <a>≪	-6-	Ic (Integra	ted circuit)	> S	mall S	cale I	ntegration	on (SSI) 4	< 10 hau	nsistor
	8	-0-			n	1edlum	\t	м	(MCI)-	→ 10 -100	trans
	<u></u>	-0-	<u></u>			arge	11		- (ZSI)	> 100 - 10,	k frans
	(<u>a</u>)				. •	leny la	rge "	**	(VLSI) -	→ >10k	brans
	(3)										
	<u>(</u>		* Block diag	gram of a c	omputer	· ·					
	(2)			CPU/UP	f		·				
	9		JP	ALU	0/9						·
	(j.)		Devices	<i>C</i> U	Devic	25	_				
	()			Registers.	_ :	_	-				
	<u></u>		Ex key board		EX. M		-			_	
	() ()		Mouse			splay					• •. •
1			Scanner	Memory!		nter					·
	(*)		Joystick		<u></u>	eakers.					
	(4)		44			· · · · · ·					
1	٠		→ Up. it is a				•	_			17
	(3)			ALU, CU & Re	~ 0			_			14
	(3)	-		up, memory are meant f							
	4	-		as Memori	•	3,019	<u>4644 (</u>	Slowase	nerve tin	A are w	-1
	(3)	-		up some me		n be t	resent	inside	to chose / L	Inid Isea	uenHu
	()			or Instruct					1-21-1-1	1014 6.4	
41,114,14				, , , , , , , , , , , , , , , , , , , ,	·		Γ]
2000.002	(3)		* Basics for	subject :							
4	()		· Bit -> Bi		(0/1)						
1			· Nibble -	group of 4	bits		L				<u> </u>
1	(3)		· Byte>	group of 8	bits/2	Nibble	2				
110000			· Word length	v						sod sozz	allely
XXXXXXX	*		· · · · · · · · · · · · · · · · · · ·	at a	time !	g it d	epends	on lep	1	····	
3	(3)						:				
T TOTAL	(j)										
SOME SECTION	(함).										
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- Intel is the first company who integrated ALU, CU and Registers in a	
single package.	
1971 - Intel 4004 - 4 bit UP. (works on two 4 bit datas) ie word	
1972 -> Intel 8008 -> 8 bit Up.) is 4 bit	
1974 -> Intel 8080 -> 8 bit Up. > Word length of 8 bits / + byte	_
1976/77 -> Intel 8025 -> 8 bit UP	
1978 -> Intel 8086 -> 16 bit Up> Word length of 16 bits/2 bytes	<u> </u>
8088, 80186, 80286, 80886 (32 bit MP)	
Pentium, Dual core, (13, is, 17) (64 bit Up)	
J S 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	
Dual core -> single IC of up internally contains & CPU's.	
quad core -> " " " 4 cpp's.	
octa cose -> " " " " 8 cpu's.	
Deca core " " " lo cpu's (Pol7 lau	nched @
by Lenov	
* Difference between Uprocessor & Ucontrollers:	
Difference Bequeen suprocessor 2 successors 2	
Timers ALU Memony	
Timers ALU Memory	
Counters Registers	©
Tologlasina Fa Dac Abe	
Interfacing Ex DAC, ADC	
Circults Encoders Buffers	
Microconholler.	
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8	<u> </u>	
(6)	6	
	Microprocessor:	Microconholler:
	→ It has ALU, CU and Registers.	-> It has ALU, CU and Registers_
*	→ No Internal Memory	- Has Internal on board memory.
	→ No Interfacing circuits, Timeris &	-> Has interfacing chts, Timers/
(2)	counters.	counters.
	-> Used for general purpose application.	-> Used for specific purpose applications
⊕	-> Ex. Intel 8085, 17, MC680,	→ Ex. TMS 1000 (4 bit), Intel 8051 (861)
(2)	780 (Zilop), Fairchild, Rockwell,	Intel 20196 (16 Lit), ATRIGET, Motorolle
9	National Cemiconductor, Phillips, Toshik	'
(2)	gualcomm, Snapdragon.	PIC → 8 bit & 16 bit.
0		
0		data are stored in a memory, there
(9)		Von-Neumann / Princeton Architecture.
(4)	•	Harvard Architecture
	Von Neuman architecture uses the	same memory for data & Programme.
(a)	Ex- Intel 8085 & Intel 8086 LL	
(herent memories for add (MIII) 4
9	Ex - Intel 8051 Mcontroller.	
(9)	EX - The Rost Manifestion.	
(4)	* Memory:	
(6)	-: Memory	÷ .
0		
(2)	Primary / Sweendary M/M	Secondary Memory.
(2)		
0	RAM ROM.	
٩	Static RAM (SRAM)	Magnetic Hoppy Hard CD DVD BRD
8	Dynamic RAM	tape disc disc! Digital (Blue Ray)
		Magnetidiscs ! Versalile Disc) {
₩	•	omanent !
***	1 1 1 1 1 1 1 1 1	EPROM optical disc
٠	€ PROM	/ LL1 N VIVI.
(<u>(</u>)		
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Secondary Memories:	
-> Magneti cape, Floppy disc and Ha	rddiscs -> Magnetism principle for storing
	data.
-> CD, DVD, BRD -> Optical/Ligh	t prinaple for storing data.
	3/15 GB; BRD -> 25 GB/50GB.
- for writing - High intensity Lie	pht is used (writing is called burning).
for Reading -> Low Intensity Li	
- Depending on the wavelength of l	right storage capacity is decided
(Wavelength of light) ~	(D→780 nm,
	(storage Capacity) DVD->635nm, BRD->
- data'i is stored as pit an	d data o' is stored as 'blank'. 405 nm)
	are used as materials for writing and
errasing also high intensity digt	
R Primary Memories - Primary	
Both RAM & ROM are Random acc	cessible memories ie time taken to
access any of the memory location is	
) RAM (Random Access Memon	•
- It is also known as Read-Write	/ temperary / Volatile memory
- The data is present only with a	
Static RAM (SRAM) :-	Dynamic RAM (DRAM):
Data is stored as Voltage	-> Data is stored as charge between
HipHops are used.	gate to substrate of a Mas transistor
1 memory cell may have 3-6 frans	
tors ie 2BIT'S & ? Registeres or	setze shed trequently.
4 Mos Transistors.	-> 1 memory cell have only one
· Less density / storage capacity.	transistor.
> Faster than DRAM	-> more density / storage capacity
> More power consumption & cost	→ slow in operation.
)	-> less power consumption and cost-
	Ex, used in Laptops.

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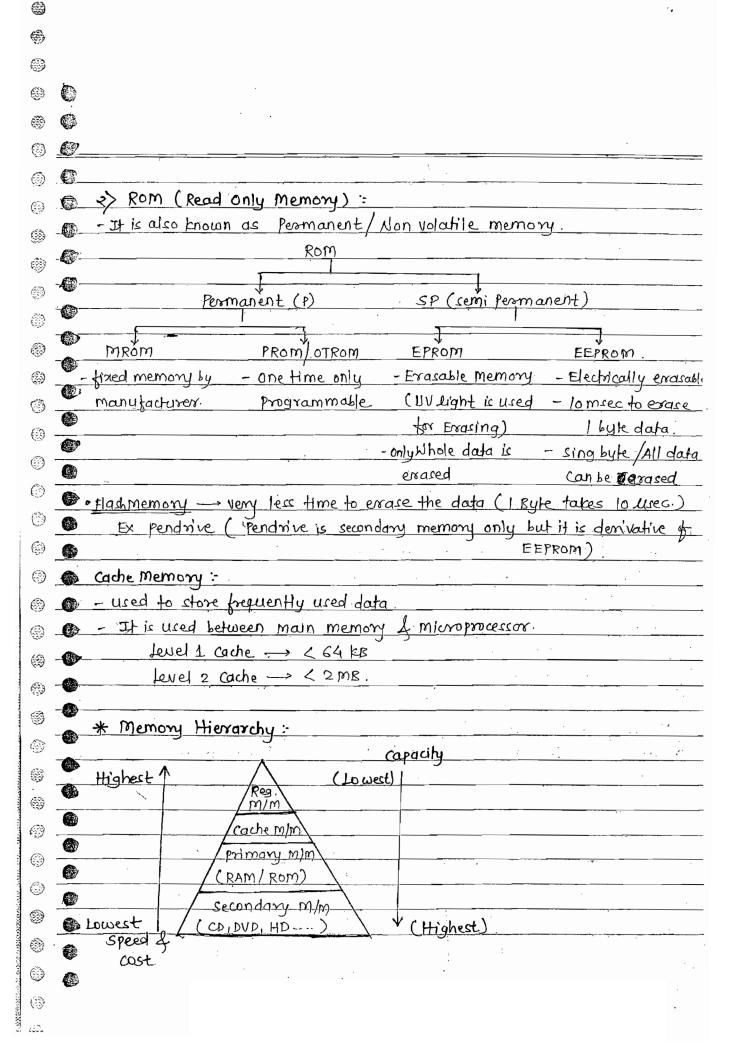
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* Basic ope	rations of micropr	DCESSOY :-		
	· ,	•	are the opendes (opena	Hond
		my code used to pe	•	
	ration of Up is also			
	ine cycles			
		110 device	= UP = Memory	_
) opcode fe	tch :	4		
•	/Accessing instruction	in le.	9	
,	_	m memory into pr	ocessor. (In some	
. ,		also be completed in	_	
2) Memory				
,	Accessing data fro	m memory.		1
Memory				
	Transfering data to	memory.		•
4) I/O Rea	· —			
,	·	m Ilp ports or Ilo	devices.	
/	dicates connection			
s) Ilo Writ	•	0		
	Transferring data t	o ole port.		
/-			id furite either with	
	memory or Hod		,	_
* Number	Sustems :		No. 10 10 10 10 10	
Decimal:	Binary:	actor =	Hexadecimal:	
-Base 10	- Bace ?	-Base 8	-Bace 16.	
0	$0 \rightarrow (0)_{10}$	0 -> (0)10	0 -> (0)10	
	1 -> (1)/0		1	
9_	10 ->(2)10	7 -(7)/0	$9 \longrightarrow (9)_{10}$	
10	$11 \rightarrow (3)_{10}$	10 - (8)10	A → (10) ₁₀	6
11	100 -> (4)/0	$11 \longrightarrow (9)_{10}$	B	
			$\begin{array}{c} C \longrightarrow (12)_{10} \\ D \longrightarrow (13)_{10} \end{array}$	
	· · · · · · · · · · · · · · · · · · ·		E - (4)10	
•			F - (1x)	•

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(2)		· converting decimal value to other number system.
®		method -> 1) divide the decimal value with base of Required of no system
(<u> </u>	and consider the Reminder from Last to first.
(4)		$\xrightarrow{EX} \rightarrow (14)_{10} \rightarrow (?)_{2} \qquad \xrightarrow{EX} (79)_{10} \rightarrow (?)_{H}$
		2 14
		$270 : (14)_{10} = (1110)_{2} 16415 = (79)_{10} = (4F)_{1}$
*	-@-	2 3 1 1 1 1
(3)		2 0 1 1
٠		
0		- Converting other durches guden to decided Value
0	•	· Converting other Number system to decimal value. Method ->
(3)	•	Manage
٨		
(4)		
9		
0		
	-	
		· Additioned of Hexadecimal Numbersym: comy
3	-	Tip 1 -> 'F' plux anything is written as "If (that no minus 1)
1	-	EX: 1) F H 2) F H 3) F H
		(8) minus 1=7 9 H 4 H
9		17 4 (18) H (13) H
		Tip2 -> 10 H' Plus 'x'H is conitten as 12"H
		EX: 10 H 10 B
	•	18 H 1 F H
**		
	0	

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(6)

	9
EX. B 4 D 7 H	
EX. B4D7 H + 516A H	
(10641) _H	
1 2's compl	
que - Find the 1's complement of given Binary no. (01110100)	
→ 01110100	
10007011->13 complement	
T	
(10001100) -> 2's complement = 1's complement + (1) at LSB.	
In general, n's complement = (n-1)'s complement +1	
'n's complement means -ve value of that number.	•
que: find (-74H)?	•
-> (74) H means 16's complement of 74 = 15's complement + 1	
FF H	
- 74 H	
8B -> 15's complem	
(8CH) (-74)H= (8C)H	
Short cut method - substract the 'LSB' from 16 (ie (10)H) and Remain)hage
bits from F	
Ex find(-3AP7) H = 8	-
F F F (10)H	
- 3 A D 7	0
C/S/2/9 H	•
que: solve:	
1) 83 H microprocessor will down like 83+(-29)H	
-39 H	
SAH.	

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